

v01.0316

# HMC574AMS8E

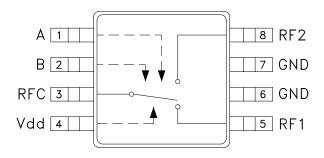
# GaAs MMIC 5 WATT T/R SWITCH DC - 3 GHz

### **Typical Applications**

The HMC574AMS8E is ideal for:

- Cellular/3G Infrastructure
- Private Mobile Radio Handsets
- WLAN, WiMAX & WiBro
- Automotive Telematics
- Test Equipment

### **Functional Diagram**



### Features

Low Insertion Loss: 0.3 dB High Third Order Intercept: +63 dBm Isolation: 30 dB Single Positive Supply: +3 to +8V SMT Package: MSOP8

### **General Description**

The HMC574AMS8E is low-cost SPDT switch in 8-lead MSOP packages for use in transmit/ receive applications which requires very low distortion at high incident power levels. The device can control signals from DC to 3 GHz and is especially suited for Cellular/3G infrastructure, WiMAX and WiBro applications with only 0.3 dB typical insertion loss. The design provides 5 watt power handling performance and +63 dBm third order intercept at +8 Volt bias. RF1 and RF2 are reflective shorts when "Off".

### Electrical Specifications, $T_{A} = +25^{\circ}$ C, Vctl = 0/+5 Vdc, Vdd = +5 Vdc (Unless Otherwise Stated), 50 Ohm System

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		0.25 0.3 0.4 0.5	0.5 0.6 0.7 0.8	dB dB dB dB
Isolation		DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz	26 24 21 16	30 28 25 20		dB dB dB dB
Return Loss		DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		35 30 25 22		dB dB dB dB
Input Power for 1dB Compression	VctI = 0/+3V VctI = 0/+5V VctI = 0/+8V	0.5 - 3.0 GHz	31 35 37	34 38 39		dBm dBm dBm
Input Third Order Intercept P <sub>tone</sub> = Two-tone Input Power (Each Tone)	$\begin{array}{l} \mbox{Vctl} = 0/{+}3\mbox{V}, \mbox{P}_{tone} = {+}23\mbox{ dBm} \\ \mbox{Vctl} = 0/{+}5\mbox{V}, \mbox{P}_{tone} = {+}27\mbox{ dBm} \\ \mbox{Vctl} = 0/{+}8\mbox{V}, \mbox{P}_{tone} = {+}27\mbox{ dBm} \end{array}$	0.5 - 3.0 GHz		63 63 63		dBm dBm dBm
Switching Characteristics		DC - 3.0 GHz				
	tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)			40 70		ns ns

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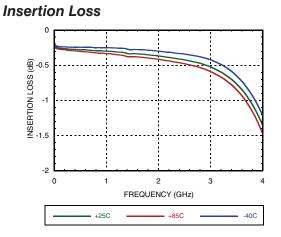
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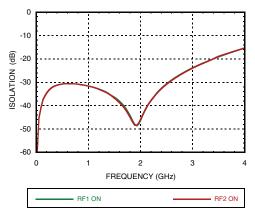
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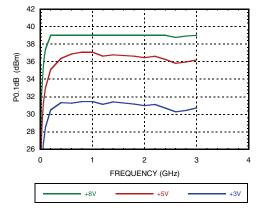
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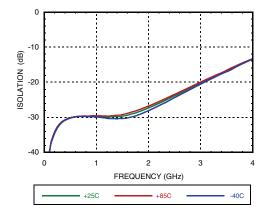
### **RF1 to RF2 Isolation**



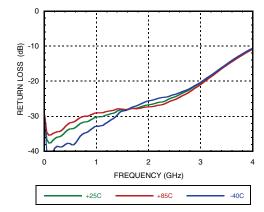
### Input P0.1dB vs. Vdd



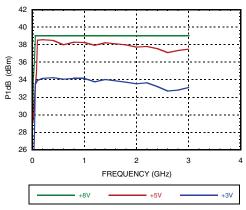
### Isolation Between RFC & RF1/RF2



### Return Loss



### Input P1dB vs. Vdd



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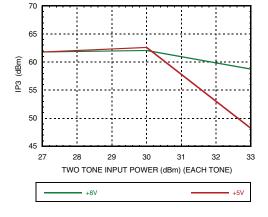


DC - 3 GHz

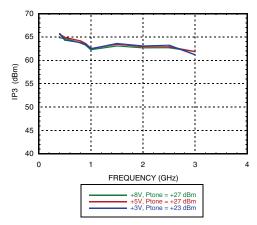
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# SWITCHES - SPDT T/R - SMT

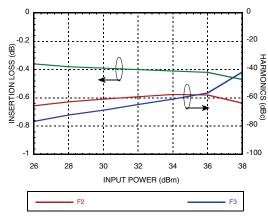
### Input IP3 vs. Input Power @ 900 MHz



### Input Third Order Intercept

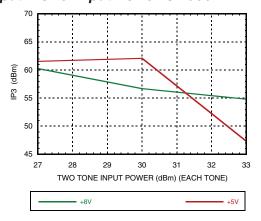


### 2nd & 3rd Harmonics @ 900 MHz Vdd = +5 Volts

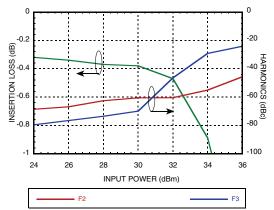


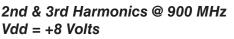
Input IP3 vs. Input Power @ 1900 MHz

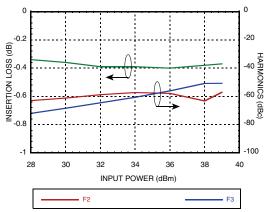
GaAs MMIC 5 WATT T/R SWITCH



### 2nd & 3rd Harmonics @ 900 MHz Vdd = +3 Volts



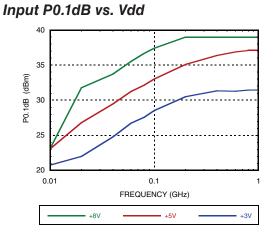




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### 

### Absolute Maximum Ratings

Max. Input Power V <sub>dd</sub> = 0/+8V	0.5 - 2.5 GHz	39 dBm	
Bias Voltage Range (Vdd)		-0.2 to +10 Vdc	
Control Voltage Range (A & B)		-0.2 to +Vdd Vdc	
Channel Temperature		150 °C	
Continuous Pdiss (T= + 85 °C) (derate 10 mW/°C above 85 °C)		0.775W	
Thermal Resistance		83.9 °C/W	
Storage Temperature		-65 to +150 °C	
Operating Temperature		-40 to +85 °C	
ESD Sensitivity (HBM)		Class 1A	

DC Blocks are required at ports RFC, RF1 and RF2



### ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

### **Bias Voltage & Current**

Input P1dB vs. Vdd

Vdd (Vdc)	Typical Idd (μA)
+3	0.5
+5	1
+8	20

### **Control Voltages**

State	Bias Condition
Low	0 to +0.2 Vdc @ 1 μA Typical
High	Vdd ± 0.2 Vdc @ 1 µA Typical

### Truth Table

Control Input (Vctl)		Signal Path State		
A	В	RFC to RF1	RFC to RF2	
High	Low	Off	On	
Low	High	On	Off	



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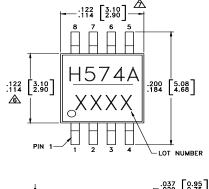
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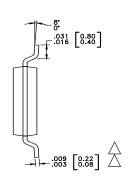
### **Outline Drawing**

[1.10]

.015 0.38 .009 0.22 TYP

.0256 [0.65] TYP







:006 0.15

NOTES:

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- 1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEAD MATERIAL: COPPER ALLOY.
- 3. LEAD PLATING: 100% MATTE TIN.
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. CHARACTERS TO BE HELVETICA MEDIUM, .030 HIGH, LASER OR WHITE INK, LOCATED
- APPROXIMATELY AS SHOWN.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- $\overline{\Delta}$  dimension does not include moldflash of 0.25mm per side.
- 8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

### **Package Information**

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC574AMS8E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[1]</sup>	<u>H574A</u> XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	А	See truth table and control voltage table.	C
2	В	See truth table and control voltage table.	
3, 5, 8	RFC, RF1, RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required.	
4	Vdd	Supply Voltage.	
6, 7	GND	This pin must be connected to RF/DC ground.	

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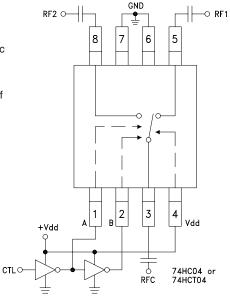
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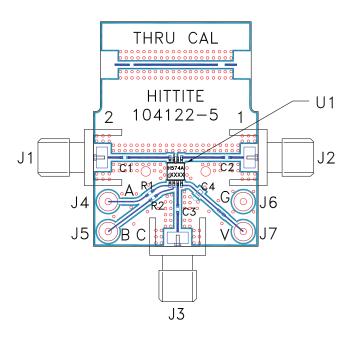
# **Typical Application Circuit**

Notes:

- Set logic gate and switch Vdd = +3V to +5V and use HCT series logic to provide a TTL driver interface.
- Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of +3 to +8 Volts applied to the CMOS logic gates and to pin 4 of the RF switch.
- 3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
- Highest RF signal power capability is achieved with Vdd set to +8V. The switch will operate properly (but at lower RF power capability) at bias voltages down to +3V.



### Evaluation Circuit Board



### List of Materials for Evaluation PCB EV1HMC574AMS8<sup>[1]</sup>

Description		
PCB Mount SMA RF Connector		
DC Pin		
100 pF capacitor, 0402 Pkg.		
10,000 pF capacitor, 0603 Pkg.		
100 Ohm resistor, 0402 Pkg.		
HMC574AMS8E T/R Switch		
104122 Evaluation PCB		

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 Ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Analog Devices Inc upon request.

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